



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



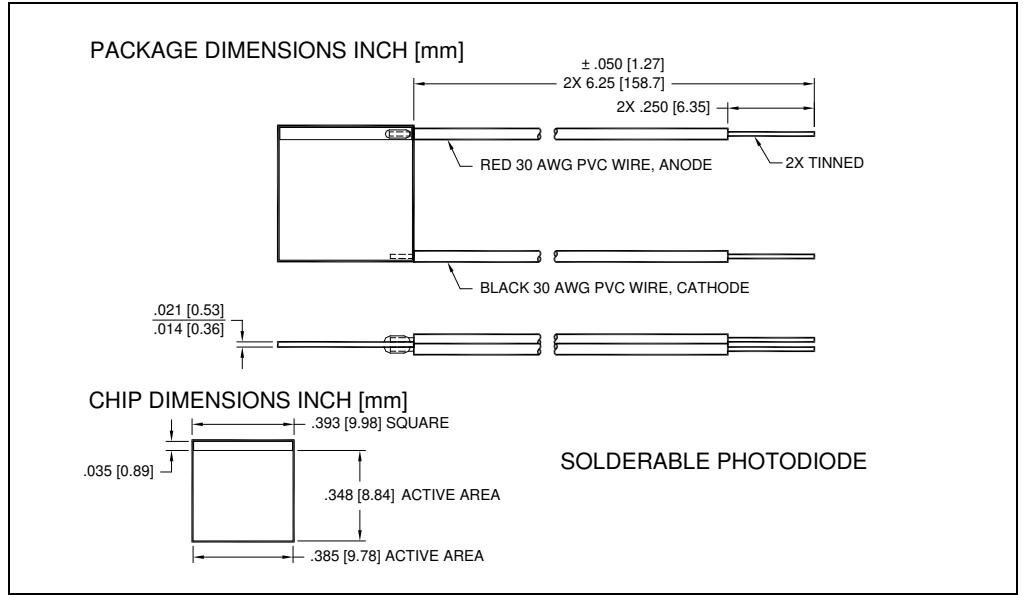
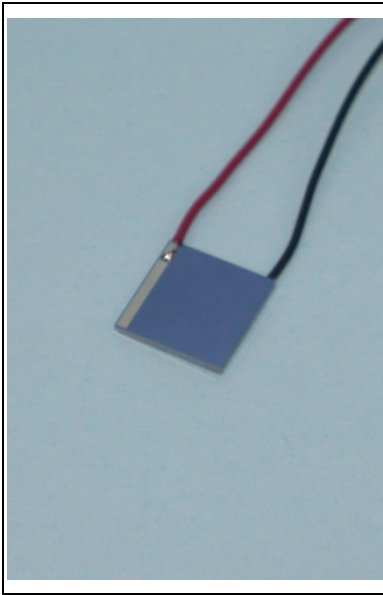
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DESCRIPTION

The **PDB-C613-2** is a silicon red enhanced solderable photodiode designed for low capacitance and high speed for photoconductive applications

FEATURES

- Red enhanced
- Photoconductive
- High quantum efficiency

RELIABILITY

This Luna high-reliability device is in principle able to meet military test requirements (Mil-STD-750, Mil-STD-883) after proper screening and group test. Contact Luna for recommendations on specific test conditions and procedures.

APPLICATIONS

- Optical encode
- Position sensor
- Industrial controls
- Instrumentation

ABSOLUTE MAXIMUM RATINGS

SYMBOL	MIN		MAX	UNITS	
Reverse Voltage	-	-	75	V	T _a = 23°C UNLESS OTHERWISE NOTED
Storage Temperature	-40	-	125	°C	-
Operating Temperature	-40	to	+100	°C	-
Soldering Temperature	-	-	+224	°C	-

OPTO-ELECTRICAL PARAMETERS

T_a = 23°C UNLESS NOTED OTHERWISE

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Short Circuit Current	H= 100 fc, 2850 K	0.70	1.0	-	mA
Dark Current	V _R = 5V	-	90	180	nA
Shunt Resistance	V _R = 10 mV	0.5	1.0	-	MΩ
Junction Capacitance	V _R =5V; f = 1 MHz	-	350	-	pF
Spectral Application Range	Spot Scan	350	-	1100	nm
Breakdown Voltage	I=10 μA	25	50	-	V
Noise Equivalent Power	V _R =0V@λ= Peak	-	3x10 ⁻¹³	-	W/Hz ^{1/2}
Response Time	RL = 50Ω, V _R = 5 V	-	50	-	nS

TYPICAL PERFORMANCE

SPECTRAL RESPONSE

